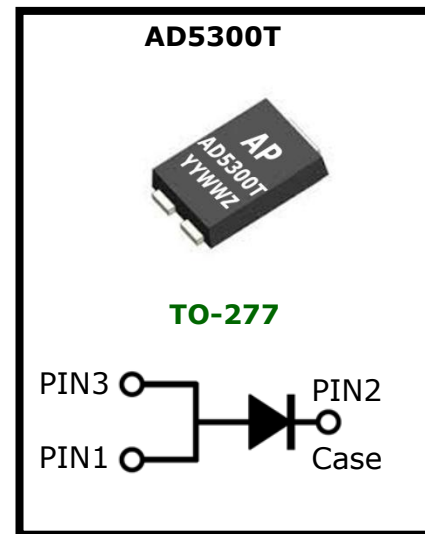


**300V 5A Ultra Low VF Schottky**

**Characteristics Summary**

Characteristics	Values	Units
IF(AV)	5	A
VRRM	300	V
VF @ 2.5A, TJ = 25°C	0.72	V, typ.
TJ, Operating Junction Temperature	-40 to +150	°C



**Features**

- Ultra Low Forward Voltage ( VF ) Drop Low Power Losses
- Low Leakage Current at high temperature.
- Reliable application for various circumstances.
- 150°C Operating Junction Temperature
- Lead Free Finish, RoHS Compliant

**Typical Applications**

Device optimized for low forward voltage drop to maximize efficiency in Power Supply applications, high frequency converters, freewheeling diodes.



## Maximum Ratings Characteristics

( TA = 25°C unless otherwise specified )

Parameter	Symbol	Values	Units
DC Blocking Voltage	V <sub>RM</sub>	300	V
Working Peak Reverse Voltage	V <sub>RWM</sub>		V
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>		V
Average Rectified Forward Current (Rated VR-20Khz Square Wave) – 50% duty cycle	I <sub>D</sub>	5	A
Peak Forward Surge Current – 1/2 60hz	I <sub>FSM</sub>	100	A
Peak Repetitive Reverse Surge Current (2uS-1Khz)	I <sub>RRM</sub>	1	A
Typical Thermal Resistance	R <sub>θJC</sub>	68	°C / W
Maximum Rate of Voltage Change ( at Rated VR)	dv/dt	10000	V/uS
Operating Junction Temperature	T <sub>J</sub>	-40 to +150	°C
Storage Junction Temperature	T <sub>STG</sub>	-40 to +150	

## Electrical Characteristics

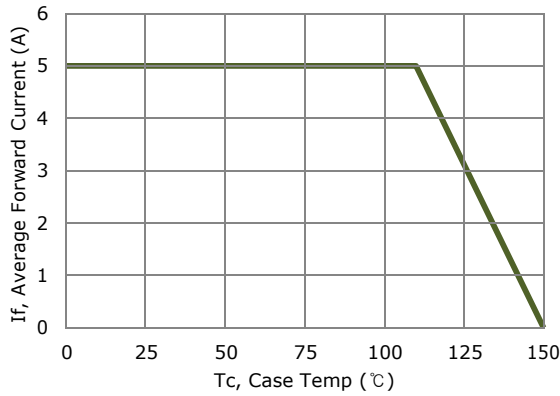
( TA = 25°C unless otherwise specified )

Parameter	Test Conditions		Symbol	Typ.	Max.	Units
Instantaneous Forward Voltage	IF = 2.5 A	T <sub>J</sub> = 25°C	V <sub>F</sub> *	0.72	0.74	V
	IF = 5 A			0.77	0.80	
	IF = 2.5 A	T <sub>J</sub> = 125°C		0.55		
	IF = 5 A			0.65		
Instantaneous Reverse Current	V <sub>R</sub> = 300V	T <sub>J</sub> = 25°C	I <sub>R</sub> *		10	uA
		T <sub>J</sub> = 125°C			10	mA
Junction Capacitance	V <sub>R</sub> = 5V, f = 1MHz		C <sub>J</sub>	321		pF

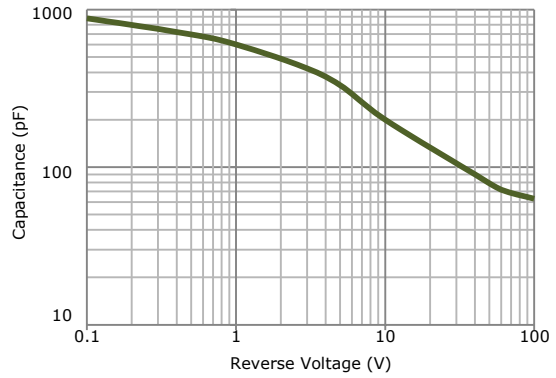
\* Pulse width < 300 uS, Duty cycle < 2%

**Characteristics Curves**

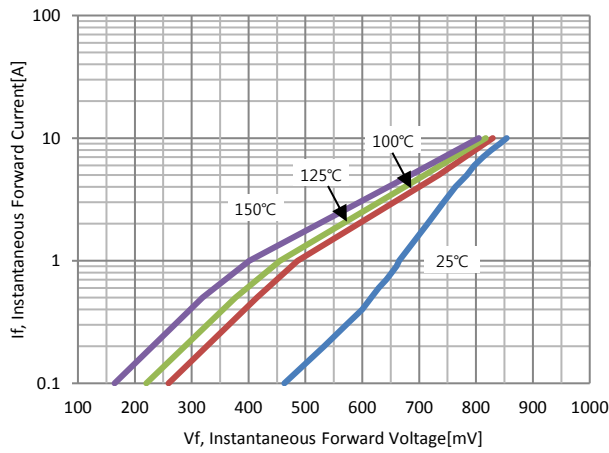
( TA = 25°C unless otherwise specified )



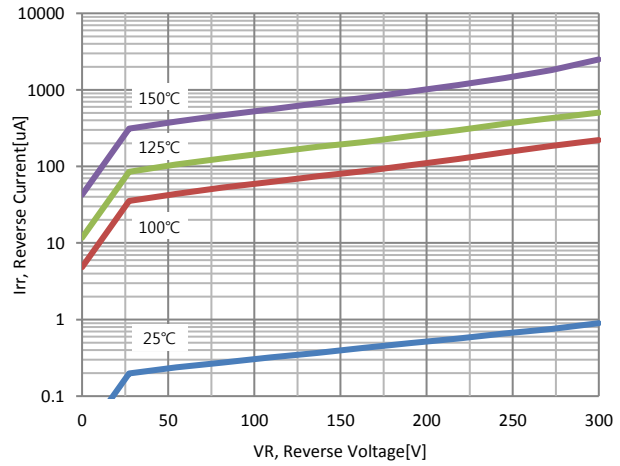
**Figure 1 : Current Derating, Case**



**Figure 2 : Typical Junction Capacitance**



**Figure 3 : Typical Forward Voltage**



**Figure 4 : Typical Reverse Current**

## Ordering Information

Part No	Package	Packing	Finish	Halogen	Packing Unit
AD5300T	TO-277	Tape & Reel	Sn	Free	5,000ea

## Marking Layout



**1<sup>ST</sup> Line : Company logo**

**2<sup>nd</sup> Line : Device name + PKG CODE**

- **T : TO-277 PKG code**

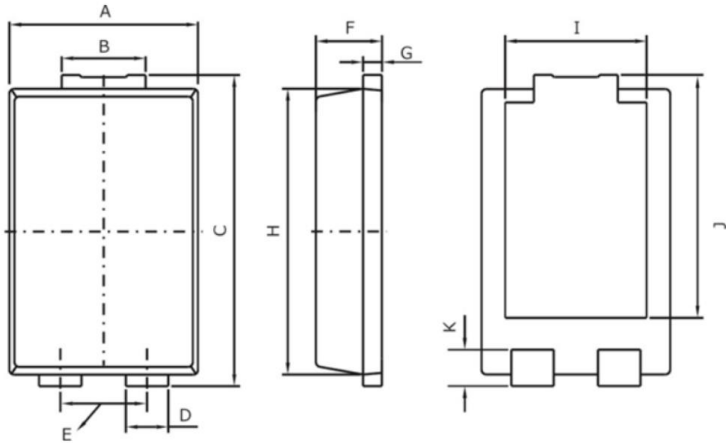
**3<sup>rd</sup> Line : Date code**

- **YY : Last two digit of calendar year**
- **WW : Work week calendar**



## Package Dimensions

### TO-277



Dim.	Min.	Max.
A	3.90	4.10
B	1.74	1.94
C	6.40	6.60
D	0.80	1.05
E	1.84 typ.	
F	1.00	1.20
G	0.35	0.45
H	5.30	5.45
I	3.05 typ.	
J	4.40 typ.	
K	0.60	0.95
All Dimensions in millimeter		

## Revision History

No	Date	Contents
0	2018-06-20	Initial Brief Datasheet Release
1	2018-11-23	Junction Capacitance Updated

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## IMPORTANT NOTICE

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